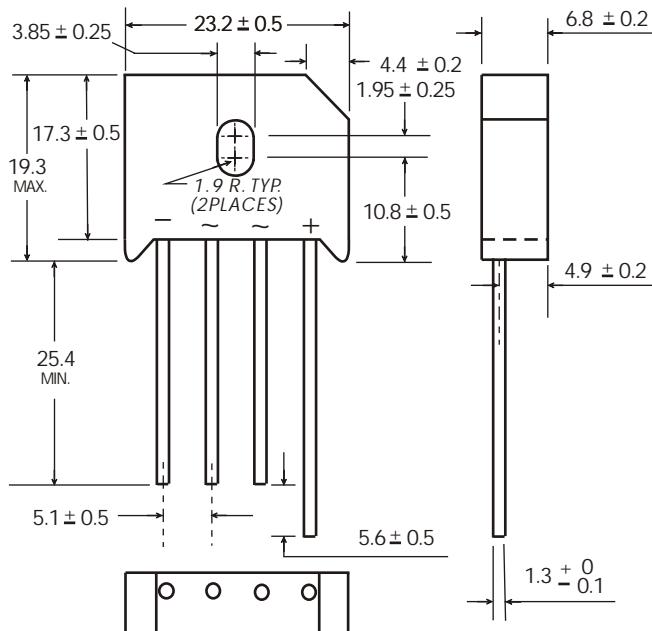


**10 A Single-Phase Silicon Bridge Rectifier**  
 Rectifier Reverse Voltage 50 to 1000V


Dimensions in millimeters(1mm =0.0394")

**Maximum Ratings & Thermal Characteristics**

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.  
 For Capacitive load derate current by 20%.

Parameter	Symbol	KBU 10005	KBU 1001	KBU 1002	KBU 1004	KBU 1006	KBU 1008	KBU 1010	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=100°C	IF(AV)				10				A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM				300				A
Rating for fusing ( t<8.3ms)	I <sup>2</sup> t				300				A <sup>2</sup> sec
Typical thermal resistance per element(1)	ReJA				2.7				°C / W
Operating junction and storage temperature range	TJ, TSTG				-55 to + 150				°C

**Electrical Characteristics**

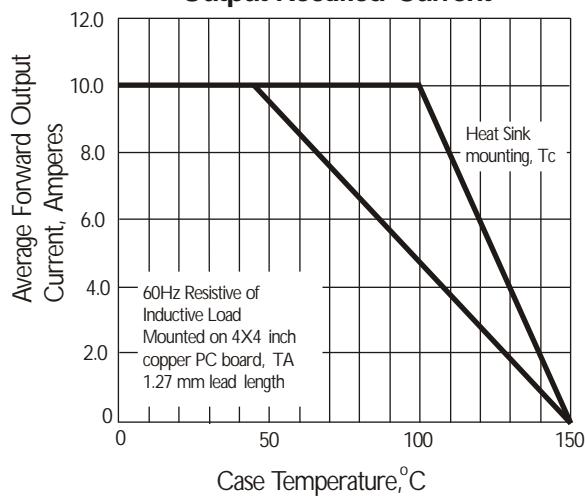
Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.  
 For Capacitive load derate by 20 %.

Parameter	Symbol	KBU 10005	KBU 1001	KBU 1002	KBU 1004	KBU 1006	KBU 1008	KBU 1010	Unit
Maximum instantaneous forward voltage drop per leg at 10A	VF				1.05				V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR				10 500				μA

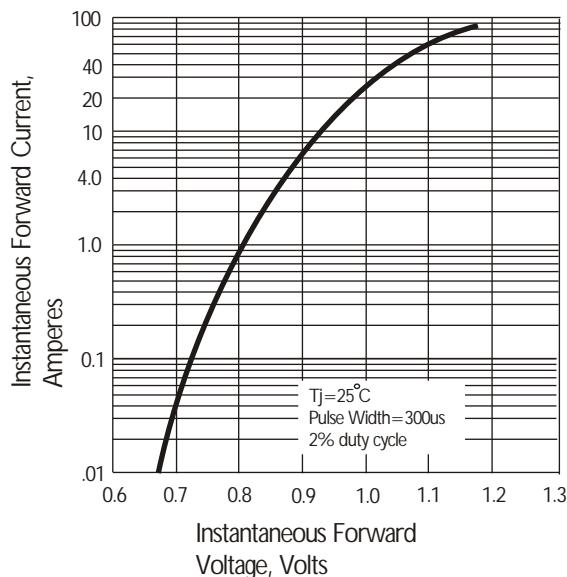
**Notes:** (1)Thermal resistance from Junction to Ambemton P.C.board mounting.

**Rating and Characteristic Curves** (  $TA=25^{\circ}\text{C}$  Unless otherwise noted )  
**KBU10005 thru KBU1010**

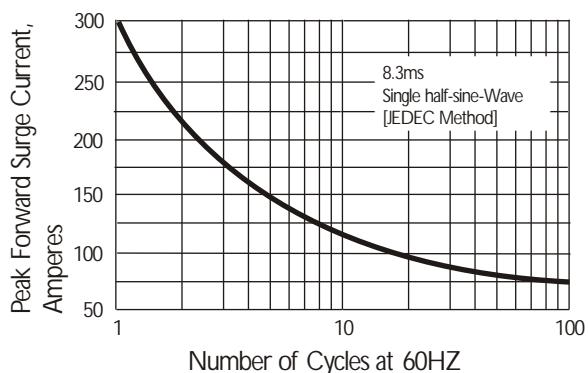
**Fig. 1 Derating Curve for Output Rectified Current**



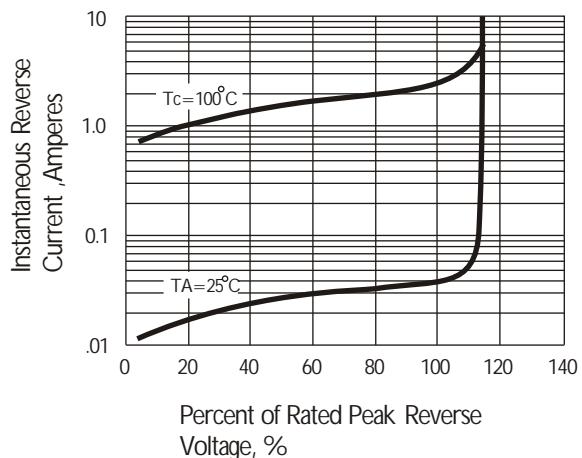
**Fig. 3 Typical Instantaneous Forward Characteristics**



**Fig. 2 Maximum Non-repetitive Peak Forward Surge Current**



**Fig. 4 Typical Reverse Characteristics**



**Fig. 5 Typical Junction Capacitance**

